



BGME160T75SD

本产品符合 AEC-Q101 标准要求

IGBT in advanced TrenchFS Technology with soft and fast recovery anti-parallel diode

具有先进 TrenchFS 技术的 IGBT 且反并联软快恢复二极管

Features:

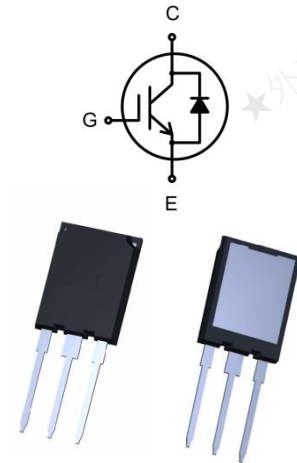
特性

- TrenchFS technology
沟槽栅场终止技术
- Low conduction and switching losses
低导通和开关损耗
- Positive temperature coefficient
饱和电压正温度系数
- Short Circuit withstand time-5 μ s
具备5 μ s短路承受能力

Applications:

应用

- Automobile motor drives
汽车电机驱动



Type 型号	$V_{CE}[V]$ 集电极-发射极电压	$I_C[A]$ 集电极电流	$V_{CEsat}[V]$ 饱和电压	$T_{jmax}[^{\circ}C]$ 最高结温	Marking 标记	Package 封装
BGME160T75SD	750	160	1.6	175	160T75SD	TO-247 Plus-3L



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Maximum Rated Values

最大额定参数

Parameter 参数	Symbol 符号	Value 值	Unit 单位
Collector-emitter voltage, $T_j \geq 25^\circ\text{C}$ 集电极-发射极电压, $T_j \geq 25^\circ\text{C}$	V_{CE}	750	V
Collector current, $T_C = 25^\circ\text{C}$ 集电极电流, $T_C = 25^\circ\text{C}$	I_C	320	A
Collector current, $T_C = 100^\circ\text{C}$ 集电极电流, $T_C = 100^\circ\text{C}$	I_C	160	
Pulsed collector current, t_p limited by $T_{j\max}$ 集电极脉冲电流, 脉宽时间受 $T_{j\max}$ 限制	I_{Cpuls}	320	
Diode forward current, $T_C = 25^\circ\text{C}$ 二极管正向电流, $T_C = 25^\circ\text{C}$	I_F	320	
Diode forward current, $T_C = 100^\circ\text{C}$ 二极管正向电流, $T_C = 100^\circ\text{C}$	I_F	160	
Diode pulsed current 二极管脉冲电流	I_{Fpuls}	640	V
Gate-emitter voltage 栅极-发射极电压	V_{GE}	± 20	
Short Circuit withstand time $V_{GE} = 15\text{V}, V_{CC} \leq 400\text{V}, T_j \leq 150^\circ\text{C}$ 短路耐受时间	t_{sc}	5	
Total power dissipation, $T_C = 25^\circ\text{C}$ 总耗散功率, $T_C = 25^\circ\text{C}$	P_{tot}	833	
Maximum junction temperature 最高结温	$T_{j\max}$	175	
Operating junction temperature 工作结温	T_{jop}	$-40 \dots +150$	$^\circ\text{C}$
Storage temperature 储存温度	T_{stg}	$-55 \dots +150$	
Soldering temperature, 1.6mm from case for 10s 焊接温度	T_{st}	260	



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Thermal Resistance

热阻

Parameter 参数	Symbol 符号	Value 值	Unit 单位
IGBT Thermal resistance junction to case IGBT 结-管壳热阻	$R_{th(j-c)}$	0.18	$^{\circ}\text{C}/\text{W}$
Diode Thermal resistance junction to case 二极管结-管壳热阻	$R_{th(j-c)}$	0.30	$^{\circ}\text{C}/\text{W}$
Thermal resistance junction to ambient 结-环境热阻	$R_{th(j-a)}$	40	$^{\circ}\text{C}/\text{W}$

Electrical Characteristic at $T_j = 25^{\circ}\text{C}$ (unless otherwise specified)

$T_j=25^{\circ}\text{C}$ 时电学特性（除非特别声明）

Parameter 参数	Symbol 符号	Conditions 条件	Value 值			Unit 单位
			Min. 最小 值	Typ. 典型 值	Max. 最大 值	

Static Characteristic

静态特性

Collector-emitter breakdown voltage 集电极-发射极击穿电压	$V_{(BR)CES}$	$V_{GE}=0\text{V},$ $I_C=100\mu\text{A}$		750	-	-	V
Collector-emitter saturation voltage 集电极-发射极饱和电压	V_{cesat}	$V_{GE}=15\text{V},$ $I_C=160\text{A}$	$T_j=25^{\circ}\text{C}$	-	1.6	2.0	
			$T_j=150^{\circ}\text{C}$	-	2.0	-	
Diode forward voltage 二极管正向电压	V_F	$V_{GE}=0\text{V},$ $I_F=160\text{A}$	$T_j=25^{\circ}\text{C}$	-	1.8	2.3	
			$T_j=150^{\circ}\text{C}$	-	1.9	-	
Gate-emitter threshold voltage 栅极-发射极阈值电压	$V_{GE(th)}$	$I_C=3\text{mA},$ $V_{CE}=V_{GE}$		5.0	6.0	7.0	
Collector-emitter cut-off current 集电极-发射极截止电流	I_{CES}	$V_{CE}=750\text{V},$ $V_{GE}=0\text{V}$		-	-	100	μA
Gate-emitter leakage current 栅极-发射极漏电流	I_{GES}	$V_{CE}=0\text{V},$ $V_{GE}=\pm 20\text{V}$		-200	-	200	nA

Dynamic Characteristic

动态特性

Input capacitance 输入电容	C_{ies}	$V_{CE}=25\text{V},$ $V_{GE}=0\text{V},$ $f=1\text{MHz}$	-	8750	-	pF
Output capacitance 输出电容	C_{oes}		-	670	-	


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Reverse transfer capacitance 反向传输电容	C_{res}		-	110	-	
Gate charge 门极电量	Q_G	$V_{CC}=400V, I_C=160A,$ $V_{GE}=15V$	-	270	-	nC
Short circuit current 短路电流	$I_{C(sc)}$	$V_{CC}=400V, V_{GE}=15V,$ $tpsc \leq 5\mu s, T_j=150^\circ C$	-	770	-	A

Switching Characteristic at $T_j=25^\circ C$ (Inductive Load)
 $T_j=25^\circ C$ 时开关特性（感性负载）

Parameter 参数	Symbol 符号	Conditions 条件	Value 值			Unit 单位
			Min. 最小值	Typ. 典型值	Max. 最大值	
IGBT Characteristic IGBT 特性						
Turn-on delay time 开通延迟时间	$t_{d(on)}$	$T_j=25^{\circ}C,$ $V_{CC}=400V,$ $I_C=160A,$ $V_{GE}=-7.5/15V,$ $R_G=4.7\Omega,$ Energy losses include “tail” and diode reverse recovery.	-	132	-	ns
Rise time 上升时间	t_r		-	89	-	
Turn-off delay time 关断延迟时间	$t_{d(off)}$		-	223	-	
Fall time 下降时间	t_f		-	108	-	
Turn-on energy 开通损耗	E_{on}		-	8.97	-	mJ
Turn-off energy 关断损耗	E_{off}		-	5.95	-	
Total switching energy 总开关损耗	E_{ts}		-	14.92	-	

Anti-Parallel Diode Characteristic
反并联二极管特性

Reverse recovery time 反向恢复时间	t_{rr}	$T_j=25^\circ C,$ $V_R=400V,$ $I_F=160A,$ $diF/dt=1500A/\mu s$	-	195	-	ns
Recovered charge 恢复电荷	Q_r		-	6.5	-	μC
Peak reverse recovery current 反向恢复峰值电流	I_{RM}		-	65	-	A
Reverse recovered energy 反向恢复损耗	E_{rec}		-	1.2	-	mJ



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Switching Characteristic at $T_J=150^{\circ}\text{C}$ (Inductive Load)

$T_J=150^{\circ}\text{C}$ 时开关特性（感性负载）

Parameter 参数	Symbol 符号	Conditions 条件	Value 值			Unit 单位
			Min. 最小值	Typ. 典型值	Max. 最大值	
IGBT Characteristic IGBT 特性						
Turn-on delay time 开通延迟时间	t _{d(on)}	T _j =150°C, V _{CC} =400V, I _C =160A, V _{GE} =-7.5/15V, R _G =4.7Ω, Energy losses include “tail” and diode reverse recovery.	-	182	-	ns
Rise time 上升时间	t _r		-	348	-	
Turn-off delay time 关断延迟时间	t _{d(off)}		-	198	-	
Fall time 下降时间	t _f		-	152	-	
Turn-on energy 开通损耗	E _{on}		-	13.88	-	mJ
Turn-off energy 关断损耗	E _{off}		-	9.22	-	
Total switching energy 总开关损耗	E _{ts}		-	23.1	-	

Anti-Parallel Diode Characteristic

反并联二极管特性

Reverse recovery time 反向恢复时间	t_{rr}	$T_J=150^{\circ}\text{C}$, $V_R=400\text{V}$, $I_F=160\text{A}$, $diF/dt=1500\text{A}/\mu\text{s}$	-	315	-	ns
Recovered charge 恢复电荷	Q_r		-	13	-	μC
Peak reverse recovery current 反向恢复峰值电流	I_{RM}		-	80	-	A
Reverse recovered energy 反向恢复损耗	E_{rec}		-	2.5	-	mJ



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ELECTRICAL CHARACTERISTICS

特性曲线

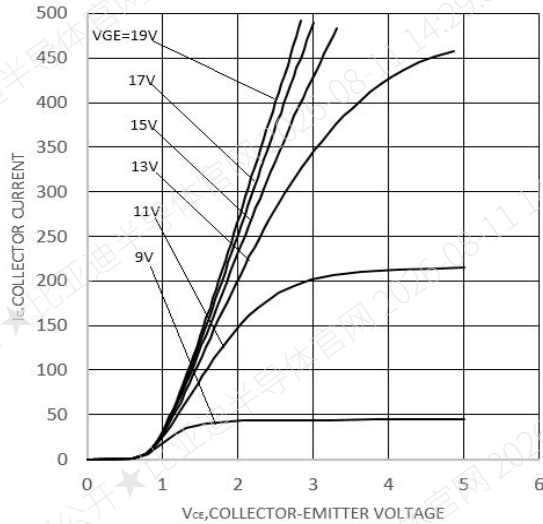


Figure 1. Typical output characteristic($T_j=25^{\circ}\text{C}$)

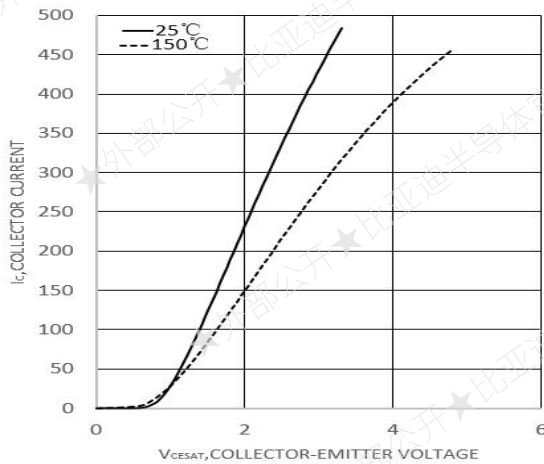


Figure 3. Typical collector-emitter saturation voltage Characteristic($V_{GE}=15\text{V}$)

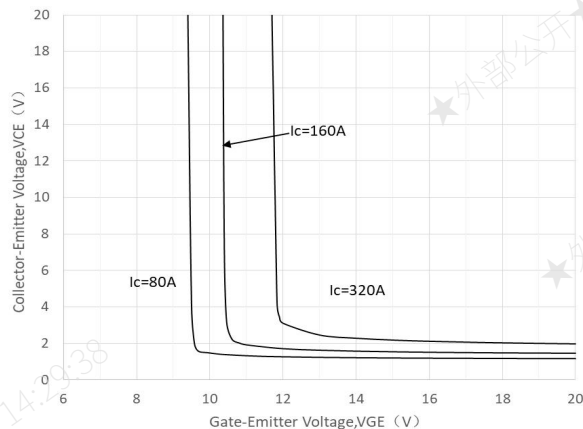


Figure 5. Saturation Voltage vs. V_{GE} ($T_j=25^{\circ}\text{C}$)

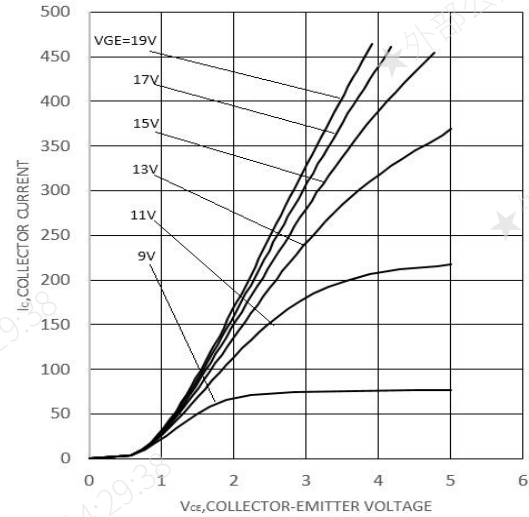


Figure 2. Typical output characteristic($T_j=150^{\circ}\text{C}$)

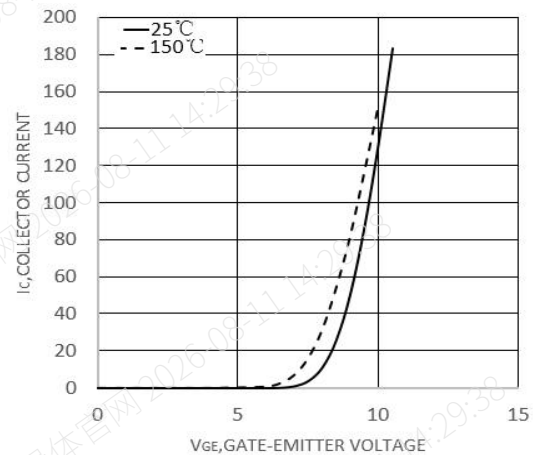


Figure 4. Typical transfer voltage($V_{CE}=20\text{V}$)

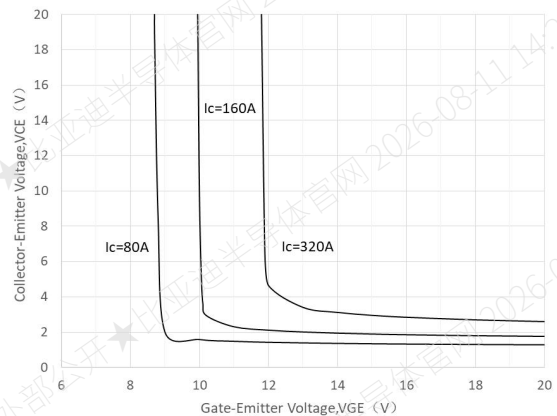


Figure 6. Saturation Voltage vs. V_{GE} ($T_j=175^{\circ}\text{C}$)



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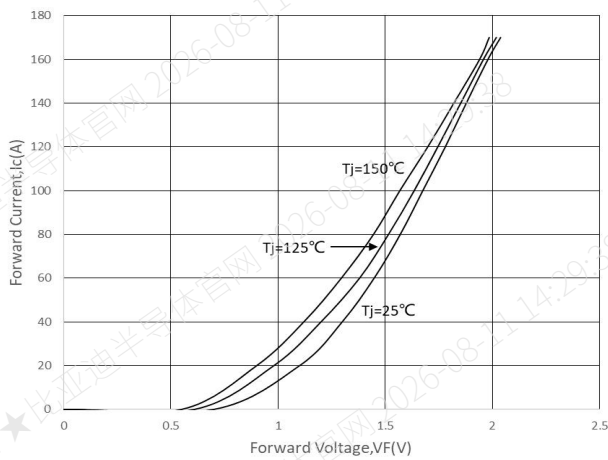


Figure 7. Forward Characteristics

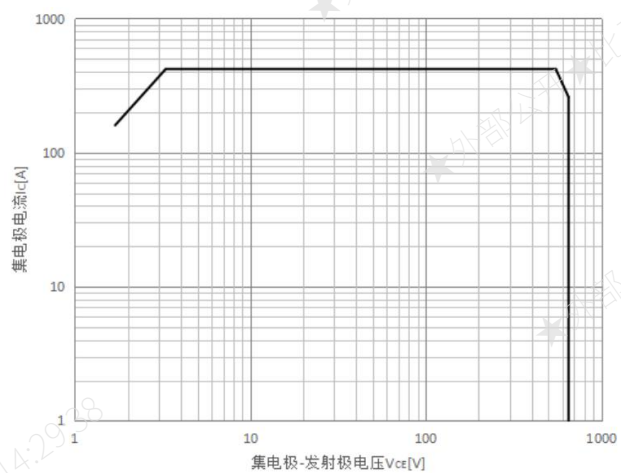


Figure 8. Turn Off Switching SOA Characteristics

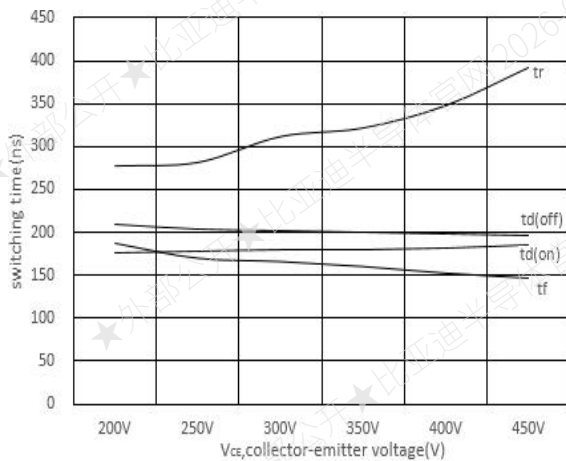


Figure 9. Typical switching time VS V_{CE}
($T_j=150^{\circ}\text{C}$, $V_{CE}=400\text{V}$, $V_{GE}=15\text{V}$, $I_C=160\text{A}$, $R_G=4.7\ \Omega$)

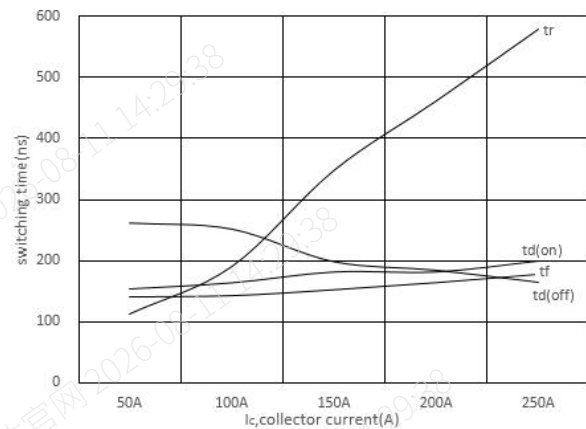


Figure 10. Typical switching times VS I_C
($T_j=150^{\circ}\text{C}$, $V_{CE}=400\text{V}$, $V_{GE}=15\text{V}$, $R_G=4.7\ \Omega$)

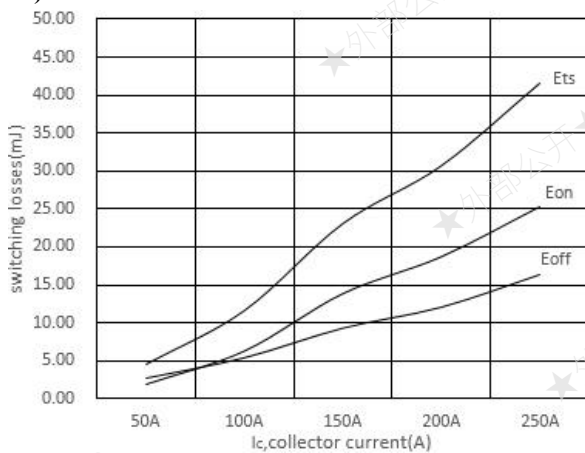


Figure 11. Typical switching energy losses VS I_C
($T_j=150^{\circ}\text{C}$, $V_{CE}=400\text{V}$, $V_{GE}=15\text{V}$, $R_G=4.7\ \Omega$)

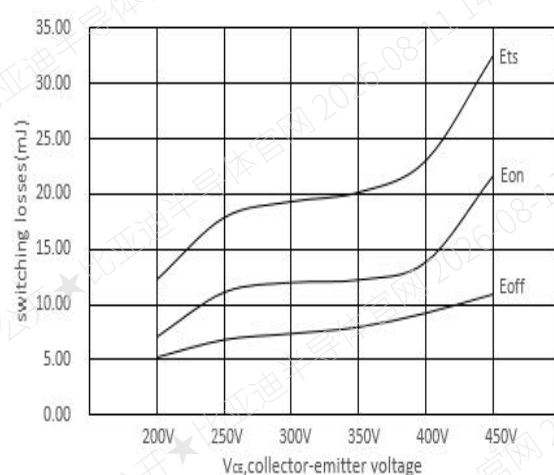


Figure 12. Typical switching energy losses VS V_{CE}
($T_j=150^{\circ}\text{C}$, $V_{GE}=15\text{V}$, $I_C=160\text{A}$, $R_G=4.7\ \Omega$)



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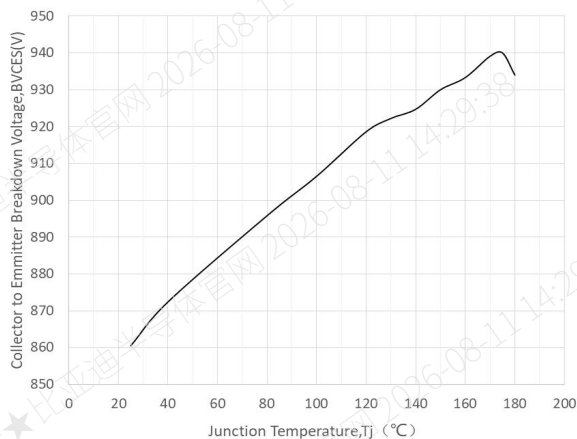


Figure 13. BVCES VS Tj (Ic=1mA)

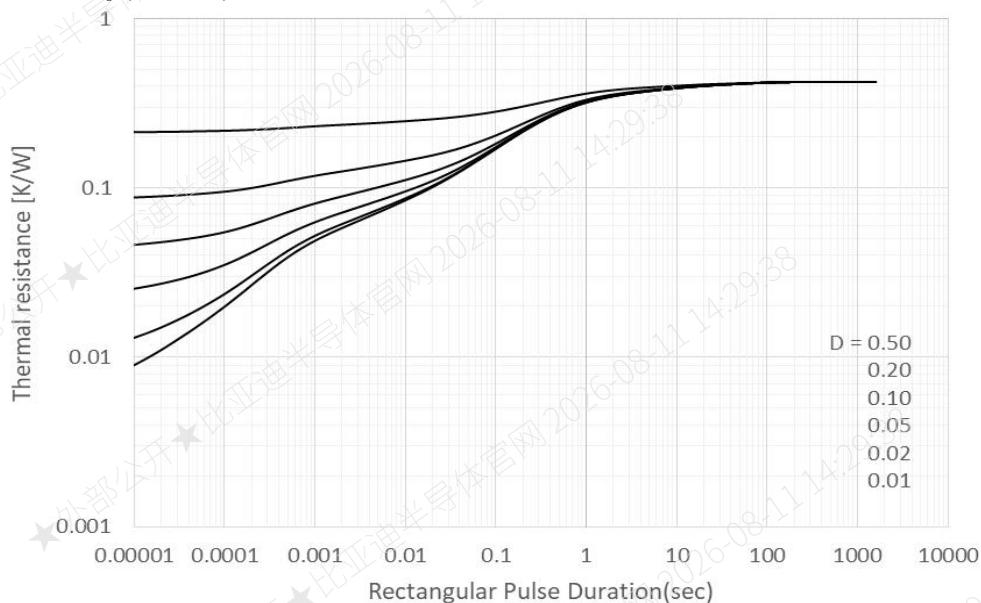


Figure 14. Transient Thermal Impedance of IGBT

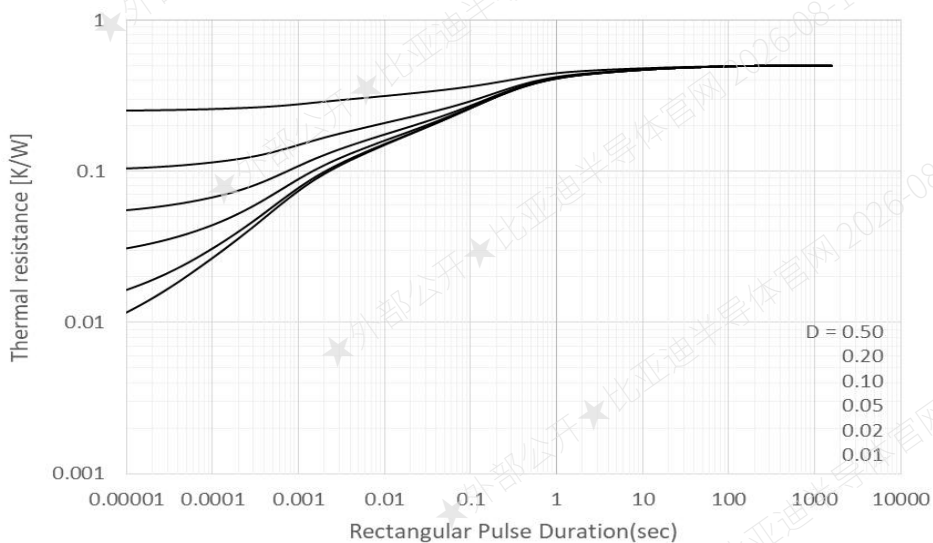


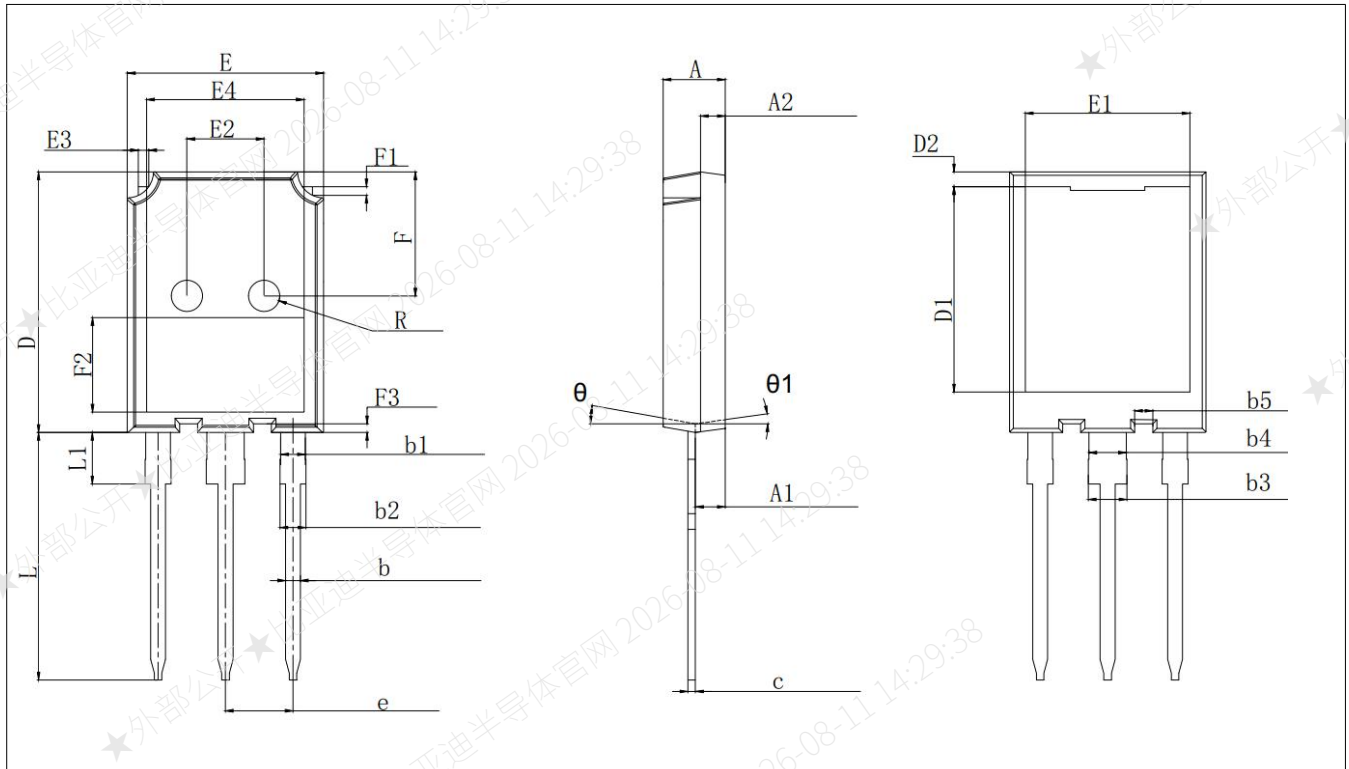
Figure 15. Transient Thermal Impedance of Diode



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TO247Plus Outline Dimensions:

TO247Plus 外形尺寸



Common Dimensions
(Units:Millimeter)

Symbol	Min.	Max.	Symbol	Min.	Max.
A	4.83	5.21	E1	13.05	14.15
A1	2.29	2.54	E2	6.1	6.3
A2	1.9	2.16	E3	0.79	1.9
b	1.07	1.33	E4	12.5	12.9
b1	1.91	2.16	F	9.8	10.2
b2	1.91	2.41	F1	0.66	0.76
b3	2.87	3.38	F2	7.4	7.8
b4	2.87	3.13	F3	0.65	0.75
b5	1.4	1.5	e	5.39	5.49
c	0.55	0.68	L	19.75	20.32
D	20.8	21.1	L1	3.7	4.19
D1	16.25	17.65	R	1.2	1.3
D2	0.5	1.24	theta	9°	11°
E	15.7	16.13	theta1	7°	9°

Note: The mold may vary little from different packaging plants, please refer to the actual product.

备注：因各封装厂的模具存在细微差异，请以实物的尺寸为准。

**BGME160T75SD****Packing****包装**

Packing	pcs/tube	tube/ inner box	inner box/ carton	pcs/carton
Tube	30	12	6	2160

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- **Warranty Period:** Unless otherwise agreed in the COOPERATION AGREEMENT or other WRITTEN DOCUMENTS, the Warranty Period for products specified in this specification shall be one year from the date of purchase if the products are properly preserved.
Special instructions: Storage Temperature: 20±5°C; Relative Humidity: 30%-60%; The product should be stored in a place away from direct light and vibration.
质保期: 除双方在合作协议或其他书面文件中另行约定外, 产品妥当保存的情况下自购买之日起, 本规格书所述产品质保期为一年。
特殊说明: 储存温度: 20±5°C; 相对湿度: 30%-60%; 产品应放置于避光地方, 避免震动。
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